

950V SJ MOSFET

1.	_ /
(🏹 -	—
\ ` -	一 ノ

Features

- Superjunction (SJ) MOSFET technology enhances efficiency
- High-voltage rating of 950V is well-suited for demanding applications
- Low gate charge enables faster switching speeds
 High-speed switching
- High-speed switching capabilities improve overall performance



Our new superjunction (SJ) MOSFET features a low gate-to-drain charge, significantly reducing conduction losses and amplifying overall efficiency.

Its superjunction MOSFET technology and on-resistance of only 1.49Ω empower engineers to design for higher voltage ratings without compromising performance.

Applications





Power Supplies

Renewable Energy

Empower Faster, More Efficient Switching with MCC's 950V SJ MOSFET



Low RDS(on) Meets Reduced Gate Charge in Popular DPAK Package



in 🖸



Superjunction MOSFET technology and on-resistance of only 1.49 Ω



Product Attributes, Parametrics & Datasheets

Product	Туре	Package	Drain- Source Voltage VDS	Max. Drain- Source On- Resistance RDS(on)	Mounting Type	Datasheet
<u>MCU1K4N95SH</u>	N-channel Superjunction Power MOSFET	DPAK (TO-252)	950V	1.49Ω	Surface- Mount (SMD)	<u>Info</u>

Applications:



- **Power adapters**
- Charging stations
- Energy monitoring
- devices
- Photovoltaic systems ٠

mccsemi.com | +818.701.4933



